

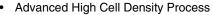


# **Dual P-Channel 12-V (D-S) MOSFET**

| PRODUCT SUMMARY     |  |                    |  |  |  |
|---------------------|--|--------------------|--|--|--|
| V <sub>DS</sub> (V) | $R_{DS(on)}\left(\Omega\right)$            | I <sub>D</sub> (A) |  |  |  |
| - 12                | $0.037 \text{ at V}_{GS} = -4.5 \text{ V}$ | - 7.7              |  |  |  |
|                     | 0.048 at V <sub>GS</sub> = - 2.5 V         | - 6.8              |  |  |  |
|                     | 0.068 at V <sub>GS</sub> = - 1.8 V         | - 5.7              |  |  |  |

#### **FEATURES**

- · Halogen-free Option Available
- TrenchFET<sup>®</sup> Power MOSFETS: 1.8 V Rated
- New Low Thermal Resistance PowerPAK<sup>®</sup> Package



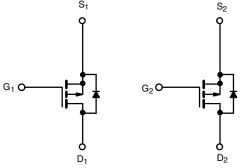
Ultra-Low R<sub>DS(on)</sub>, and High P<sub>D</sub> Capability

# Pb-free

RoHS

#### **APPLICATIONS**

- Load Switch
- PA Switch
- Battery Switch
- · Bi-Directional Switch



P-Channel MOSFET

P-Channel MOSFET

| PowerPAK 1212-8                     |
|-------------------------------------|
| 3.30 mm 3.30 mm 2 3.30 mm 2 3.30 mm |
| Bottom View                         |

Ordering Information: Si7909DN-T1-E3 (Lead (Pb)-free)

Si7909DN-T1-GE3 (Lead (Pb)-free and Halogen-free)

| ABSOLUTE MAXIMUM RATINGS T <sub>A</sub> = 25 °C, unless otherwise noted |                        |                                   |             |              |      |  |
|---|------------------------|-----------------------------------|-------------|--------------|------|--|
| Parameter   |                        | Symbol                            | 10 s        | Steady State | Unit |  |
| Drain-Source Voltage  |                        | $V_{DS}$                          | - 12        |              | V    |  |
| Gate-Source Voltage   |                        | V <sub>GS</sub>                   | ± 8         |              |      |  |
| Continuous Drain Current (T <sub>.I</sub> = 150 °C) <sup>a</sup>        | T <sub>A</sub> = 25 °C | - I <sub>D</sub>                  | - 7.7       | - 5.3        | A    |  |
| Continuous Diam Current (1) = 150 °C)                                   | T <sub>A</sub> = 85 °C |                                   | - 5.5       | - 3.8        |      |  |
| Pulsed Drain Current  |                        | I <sub>DM</sub>                   | - 20        |              | A .  |  |
| Continuous Source Current (Diode Conduction) <sup>a</sup>               |                        | I <sub>S</sub>                    | - 2.3       | - 1.1        |      |  |
| Marrian Danier Disabation d   | T <sub>A</sub> = 25 °C | - P <sub>D</sub>                  | 2.8         | 1.3          | W    |  |
| Maximum Power Dissipation <sup>a</sup>                                  | T <sub>A</sub> = 85 °C |                                   | 1.5         | 0.85         |      |  |
| Operating Junction and Storage Temperature Range                        |                        | T <sub>J</sub> , T <sub>stg</sub> | - 55 to 150 |              | °C   |  |
| Soldering Recommendations <sup>b, c</sup>                               |                        |                                   | 260         |              |      |  |

| THERMAL RESISTANCE RATINGS               |              |                     |         |         |      |
|--|--------------|---------------------|---------|---------|------|
| Parameter                                |              | Symbol              | Typical | Maximum | Unit |
| Manifestor to Ambrida                    | t ≤ 10 s     | - R <sub>thJA</sub> | 35      | 44      | °C/W |
| Maximum Junction-to-Ambient <sup>a</sup> | Steady State |                     | 75      | 94      |      |
| Maximum Junction-to-Case                 | Steady State | $R_{thJC}$          | 4       | 5       |      |

#### Notes:

- a. Surface Mounted on 1" x 1" FR4 board.
- b. See Solder Profile (http://www.vishay.com/ppg?73257). The PowerPAK 1212-8 is a leadless package. The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection.
- c. Rework Conditions: manual soldering with a soldering iron is not recommended for leadless components.

# Vishay Siliconix



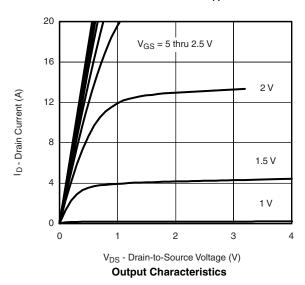
| <b>SPECIFICATIONS</b> T <sub>J</sub> = 25 °C, unless otherwise noted |                     |  |        |       |       |      |  |
|--|---------------------|--|--------|-------|-------|------|--|
| Parameter  | Symbol              | Test Conditions Min.   |        | Тур.  | Max.  | Unit |  |
| Static   |                     |  |        |       |       |      |  |
| Gate Threshold Voltage   | $V_{GS(th)}$        | $V_{DS} = V_{GS}, I_{D} = -700 \mu A$                                    | - 0.40 |       | - 1.0 | V    |  |
| Gate-Body Leakage  | I <sub>GSS</sub>    | $V_{DS} = 0 V$ , $V_{GS} = \pm 8 V$                                      |        |       | ± 100 | nA   |  |
| Zero Gate Voltage Drain Current                                      |                     | $V_{DS} = -12 \text{ V}, V_{GS} = 0 \text{ V}$                           | -1     |       |       |      |  |
|  | I <sub>DSS</sub>    | V <sub>DS</sub> = - 12 V, V <sub>GS</sub> = 0 V, T <sub>J</sub> = 85 °C  |        |       | - 5   | μΑ   |  |
| On-State Drain Current <sup>a</sup>                                  | I <sub>D(on)</sub>  | $V_{DS} \le -5 \text{ V}, V_{GS} = -4.5 \text{ V}$                       | - 20   |       |       | Α    |  |
| Drain-Source On-State Resistance <sup>a</sup>                        |                     | V <sub>GS</sub> = - 4.5 V, I <sub>D</sub> = - 7.7 A                      |        | 0.031 | 0.037 | Ω    |  |
|  | R <sub>DS(on)</sub> | V <sub>GS</sub> = - 2.5 V, I <sub>D</sub> = - 6.8 A                      |        | 0.040 | 0.048 |      |  |
|  |                     | V <sub>GS</sub> = - 1.8 V, I <sub>D</sub> = - 3.0 A                      |        | 0.057 | 0.068 |      |  |
| Forward Transconductance <sup>a</sup>                                | 9 <sub>fs</sub>     | V <sub>DS</sub> = - 6 V, I <sub>D</sub> = - 7.7 A                        |        | 17    |       | S    |  |
| Diode Forward Voltage <sup>a</sup>                                   | $V_{SD}$            | I <sub>S</sub> = - 2.3 A, V <sub>GS</sub> = 0 V                          |        | - 0.7 | - 1.2 | V    |  |
| Dynamic <sup>b</sup>   |                     |  |        |       |       |      |  |
| Total Gate Charge  | $Q_g$               |  |        | 15.5  | 24    |      |  |
| Gate-Source Charge   | $Q_{gs}$            | $V_{DS} = -6 \text{ V}, V_{GS} = -4.5 \text{ V}, I_{D} = -7.7 \text{ A}$ |        | 2.5   |       | nC   |  |
| Gate-Drain Charge  | $Q_{gd}$            |  |        | 4.3   |       |      |  |
| Turn-On Delay Time   | t <sub>d(on)</sub>  |  |        | 25    | 40    |      |  |
| Rise Time  | t <sub>r</sub>      | $V_{DD}$ = - 6 V, $R_L$ = 6 $\Omega$                                     |        | 45    | 70    |      |  |
| Turn-Off DelayTime   | t <sub>d(off)</sub> | $I_D \cong$ - 1 A, $V_{GEN}$ = - 4.5 V, $R_G$ = 6 $\Omega$               |        | 90    | 135   | ns   |  |
| Fall Time  | t <sub>f</sub>      |  |        | 85    | 130   |      |  |
| Source-Drain Reverse Recovery Time                                   | t <sub>rr</sub>     | I <sub>F</sub> = - 2.3 A, dl/dt = 100 A/μs                               |        | 70    | 110   |      |  |

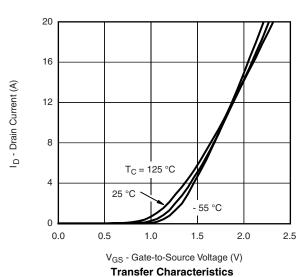
#### Notes

- a. Pulse test; pulse width  $\leq 300~\mu s,$  duty cycle  $\leq 2~\%.$
- b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

#### **TYPICAL CHARACTERISTICS** $T_A = 25 \, ^{\circ}C$ , unless otherwise noted



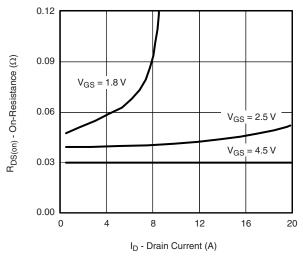




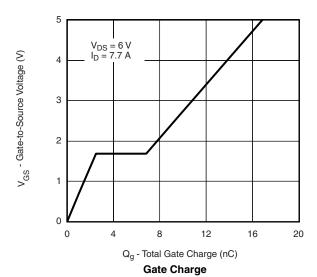


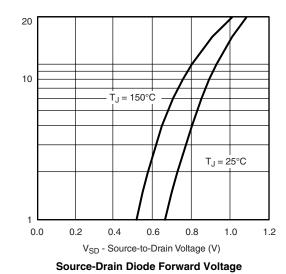


#### **TYPICAL CHARACTERISTICS** $T_A = 25$ °C, unless otherwise noted



#### On-Resistance vs. Drain Current





2400

1800

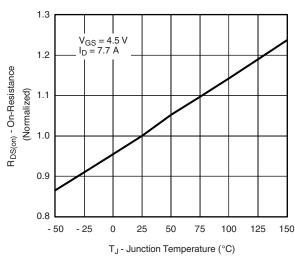
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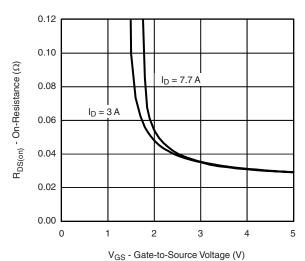
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VDS - Drain-to-Source Voltage (V)

Capacitance



On-Resistance vs. Junction Temperature



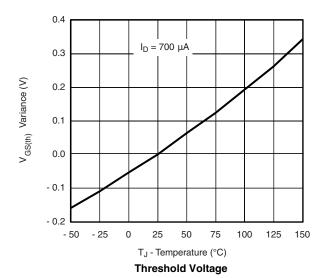
On-Resistance vs. Gate-to-Source Voltage

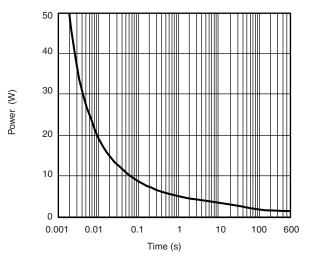
Is - Source Current (A)

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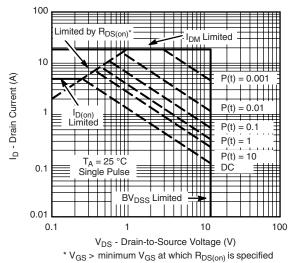
# VISHAY

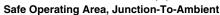
## **TYPICAL CHARACTERISTICS** $T_A = 25 \, ^{\circ}C$ , unless otherwise noted

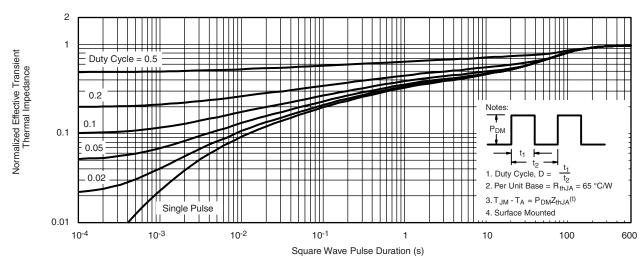




Single Pulse Power, Junction-to-Ambient



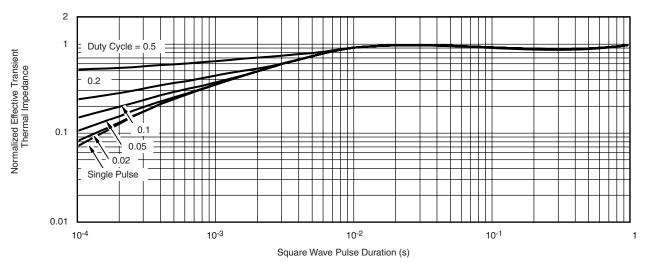




Normalized Thermal Transient Impedance, Junction-to-Ambient



#### **TYPICAL CHARACTERISTICS** $T_A = 25 \, ^{\circ}C$ , unless otherwise noted



Normalized Thermal Transient Impedance, Junction-to-Case

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